

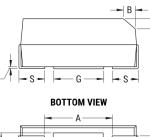
## T498C476K010AGE800

T498, Tantalum, MnO2 Tantalum, High Temperature, 47 uF, 10%, 10 VDC, SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200, N/A, 800 mOhms, 6032, Height Max = 2.8mm

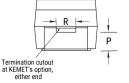
**CATHODE (-) END VIEW** 

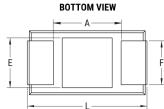


ANODE (+) END VIEW



SIDE VIEW







Click here for the 3D model.

Dimensions	
Footprint	6032
L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
Н	2.5mm +/-0.3mm
т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
А	3.1mm MIN
В	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
Р	0.9mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

т

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T498
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Gold
Qualifications	AEC-Q200
AEC-Q200	Yes
Component Weight	224.48 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	47 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 8 VDC (125C), 6.7 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
<b>Dissipation Factor</b>	4.5% 120Hz 25C
Failure Rate	N/A
Resistance	800 mOhms (100kHz 25C)
Ripple Current	371 mA (rms, 100kHz 25C), 333.9 mA (rms, 85C), 111.3 mA (rms, 150C)
Leakage Current	4.7 uA (5min 25°C)

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